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### What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

### Details

Details	
Product Status	Active
Core Processor	RL78
Core Size	16-Bit
Speed	32MHz
Connectivity	CSI, I <sup>2</sup> C, LINbus, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	34
Program Memory Size	96KB (96K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	8K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 10x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-LQFP
Supplier Device Package	48-LFQFP (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f101gfdfb-30

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Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

	1	-1	T	(7/12)
Pin count	Package	Data flash	Fields of Application	Ordering Part Number
52 pins	52-pin plastic LQFP (10 × 10	Mounted	A	R5F100JCAFA#V0, R5F100JDAFA#V0, R5F100JEAFA#V0, R5F100JFAFA#V0, R5F100JGAFA#V0, R5F100JHAFA#V0,
	mm, 0.65 mm			R5F100JJAFA#V0, R5F100JKAFA#V0, R5F100JLAFA#V0
	pitch)			R5F100JCAFA#X0, R5F100JDAFA#X0, R5F100JEAFA#X0,
				R5F100JFAFA#X0, R5F100JGAFA#X0, R5F100JHAFA#X0,
				R5F100JJAFA#X0, R5F100JKAFA#X0, R5F100JLAFA#X0
			D	R5F100JCDFA#V0, R5F100JDDFA#V0, R5F100JEDFA#V0,
				R5F100JFDFA#V0, R5F100JGDFA#V0, R5F100JHDFA#V0,
				R5F100JJDFA#V0, R5F100JKDFA#V0, R5F100JLDFA#V0
				R5F100JCDFA#X0, R5F100JDDFA#X0, R5F100JEDFA#X0,
				R5F100JFDFA#X0, R5F100JGDFA#X0, R5F100JHDFA#X0,
				R5F100JJDFA#X0, R5F100JKDFA#X0, R5F100JLDFA#X0
			G	R5F100JCGFA#V0, R5F100JDGFA#V0, R5F100JEGFA#V0,
				R5F100JFGFA#V0,R5F100JGGFA#V0,R5F100JHGFA#V0,
				R5F100JJGFA#V0
				R5F100JCGFA#X0, R5F100JDGFA#X0, R5F100JEGFA#X0,
				R5F100JFGFA#X0,R5F100JGGFA#X0, R5F100JHGFA#X0,
				R5F100JJGFA#X0
		Not	А	R5F101JCAFA#V0, R5F101JDAFA#V0, R5F101JEAFA#V0,
		mounted		R5F101JFAFA#V0, R5F101JGAFA#V0, R5F101JHAFA#V0,
				R5F101JJAFA#V0, R5F101JKAFA#V0, R5F101JLAFA#V0
				R5F101JCAFA#X0, R5F101JDAFA#X0, R5F101JEAFA#X0,
				R5F101JFAFA#X0, R5F101JGAFA#X0, R5F101JHAFA#X0,
				R5F101JJAFA#X0, R5F101JKAFA#X0, R5F101JLAFA#X0
			D	R5F101JCDFA#V0, R5F101JDDFA#V0, R5F101JEDFA#V0,
				R5F101JFDFA#V0, R5F101JGDFA#V0, R5F101JHDFA#V0,
				R5F101JJDFA#V0, R5F101JKDFA#V0, R5F101JLDFA#V0
				R5F101JCDFA#X0, R5F101JDDFA#X0, R5F101JEDFA#X0,
				R5F101JFDFA#X0, R5F101JGDFA#X0, R5F101JHDFA#X0,
				R5F101JJDFA#X0, R5F101JKDFA#X0, R5F101JLDFA#X0

Note For the fields of application, refer to Figure 1-1 Part Number, Memory Size, and Package of RL78/G13.

Caution The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.



Table 1-1.	List of Ordering Part Nu	umbers
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				(12/12)
Pin count	Package	Data flash	Fields of Application <sup>Note</sup>	Ordering Part Number
128 pins	128-pin plastic LFQFP (14 × 20 mm, 0.5 mm pitch)	Mounted	A	R5F100SHAFB#V0, R5F100SJAFB#V0, R5F100SKAFB#V0, R5F100SLAFB#V0 R5F100SHAFB#X0, R5F100SJAFB#X0, R5F100SKAFB#X0, R5F100SLAFB#X0 R5F100SHDFB#V0, R5F100SJDFB#V0, R5F100SKDFB#V0, R5F100SLDFB#V0 R5F100SKDFB#X0, R5F100SJDFB#X0, R5F100SKDFB#X0, R5F100SLDFB#X0
		Not mounted	D	R5F101SHAFB#V0, R5F101SJAFB#V0, R5F101SKAFB#V0, R5F101SLAFB#V0 R5F101SHAFB#X0, R5F101SJAFB#X0, R5F101SKAFB#X0, R5F101SLAFB#X0 R5F101SHDFB#V0, R5F101SJDFB#V0, R5F101SKDFB#V0, R5F101SLDFB#V0 R5F101SHDFB#X0, R5F101SLDFB#X0, R5F101SKDFB#X0, R5F101SLDFB#X0

Note For the fields of application, refer to Figure 1-1 Part Number, Memory Size, and Package of RL78/G13.

Caution The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.



### [80-pin, 100-pin, 128-pin products]

# Caution This outline describes the functions at the time when Peripheral I/O redirection register (PIOR) is set to 00H.

							(1/2)		
	Item	80-	•	100	)-pin	128-pin			
		R5F100Mx	R5F101Mx	R5F100Px	R5F101Px	R5F100Sx	R5F101Sx		
Code flash m	emory (KB)	96 te	o 512	96 t	o 512	192	to 512		
Data flash me	emory (KB)	8	_	8	-	8	-		
RAM (KB)		8 to 3	2 Note 1	8 to 3	32 Note 1	16 to 5	32 Note 1		
Address space	e	1 MB							
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (High-speed main) mode: 1 to 20 MHz ( $V_{DD} = 2.7$ to 5.5 V), HS (High-speed main) mode: 1 to 16 MHz ( $V_{DD} = 2.4$ to 5.5 V), LS (Low-speed main) mode: 1 to 8 MHz ( $V_{DD} = 1.8$ to 5.5 V), LV (Low-voltage main) mode: 1 to 4 MHz ( $V_{DD} = 1.6$ to 5.5 V)							
	High-speed on-chip oscillator	HS (High-speed LS (Low-speed	I main) mode: 1 I main) mode: 1 main) mode: 1 e main) mode: 1	to 16 MHz (V <sub>DD</sub> to 8 MHz (V <sub>DD</sub> =	= 2.4 to 5.5 V), 1.8 to 5.5 V),				
Subsystem cl	ock	XT1 (crystal) os 32.768 kHz	cillation, externa	I subsystem cloc	k input (EXCLKS	i)			
Low-speed or	n-chip oscillator	15 kHz (TYP.)							
General-purp	ose register	(8-bit register × 8) × 4 banks							
Minimum instruction execution time		0.03125 $\mu$ s (High-speed on-chip oscillator: fi $_{\rm H}$ = 32 MHz operation)							
		0.05 µs (High-speed system clock: f <sub>MX</sub> = 20 MHz operation)							
		30.5 µs (Subsystem clock: fsuB = 32.768 kHz operation)							
Instruction se	t	<ul> <li>Data transfer (8/16 bits)</li> <li>Adder and subtractor/logical operation (8/16 bits)</li> <li>Multiplication (8 bits × 8 bits)</li> <li>Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.</li> </ul>							
I/O port	Total	7	74	92		1	20		
	CMOS I/O	(N-ch O.D. I/O	64 [EV <sub>DD</sub> withstand le]: 21)	(N-ch O.D. I/O	82 [EV⊳⊳ withstand ge]: 24)	(N-ch O.D. I/O	10 [EV <sub>DD</sub> withstand ge]: 25)		
	CMOS input		5		5		5		
	CMOS output		1	1			1		
	N-ch O.D. I/O (withstand voltage: 6 V)		4		4		4		
Timer	16-bit timer	12 cha	annels	12 channels		16 ch	annels		
	Watchdog timer	1 cha	annel	1 channel		1 cha	annel		
	Real-time clock (RTC)	1 cha	annel	1 channel		1 cha	annel		
	12-bit interval timer (IT)	1 cha	annel	1 ch	annel	1 cha	annel		
	Timer output	12 channels (PWM outputs:	10 <sup>Note 2</sup> )	12 channels     16 channels       (PWM outputs: 10 Note 2)     (PWM outputs: 10 Note 2)			14 Note 2)		
	RTC output	1 channel • 1 Hz (subsyster)	tem clock: fsub =	32.768 kHz)					

**Notes 1.** The flash library uses RAM in self-programming and rewriting of the data flash memory.

The target products and start address of the RAM areas used by the flash library are shown below.

R5F100xJ, R5F101xJ (x = M, P): Start address FAF00H

R5F100xL, R5F101xL (x = M, P, S): Start address F7F00H

For the RAM areas used by the flash library, see **Self RAM list of Flash Self-Programming Library** for RL78 Family (R20UT2944).



# 2.3 DC Characteristics

# 2.3.1 Pin characteristics

Items	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Output current, high <sup>Note 1</sup>	Іон1	Per pin for P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	$1.6~V \leq EV_{DD0} \leq 5.5~V$			-10.0 Note 2	mA
		P40 to P47, P102 to P106, P120, P125 to P127, P130, P140 to P145 (When duty ≤ 70% <sup>Note 3</sup> )	$4.0~V \leq EV_{\text{DD0}} \leq 5.5~V$			-55.0	mA
			$2.7~V \leq EV_{\text{DD0}} < 4.0~V$			-10.0	mA
			$1.8~V \leq EV_{\text{DD0}} < 2.7~V$			-5.0	mA
			$1.6~V \leq EV_{\text{DD0}} < 1.8~V$			-2.5	mA
		Total of P05, P06, P10 to P17, P30, P31,				-80.0	mA
		P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100, P101, P110 to	$2.7~V \leq EV_{\text{DD0}} < 4.0~V$			-19.0	mA
		P117, P146, P147	$1.8~V \leq EV_{\text{DD0}} < 2.7~V$			-10.0	mA
		(When duty $\leq$ 70% <sup>Note 3</sup> )	$1.6~V \leq EV_{\text{DD0}} < 1.8~V$			-5.0	mA
		Total of all pins (When duty $\leq 70\%$ <sup>Note 3</sup> )	$1.6~V \leq EV_{\text{DD0}} \leq 5.5~V$			-135.0 Note 4	mA
	Іон2	Per pin for P20 to P27, P150 to P156	$1.6~V \leq V_{\text{DD}} \leq 5.5~V$			-0.1 <sup>Note 2</sup>	mA
		Total of all pins (When duty $\leq 70\%$ <sup>Note 3</sup> )	$1.6~V \leq V_{\text{DD}} \leq 5.5~V$			-1.5	mA

**Notes 1**. Value of current at which the device operation is guaranteed even if the current flows from the EV<sub>DD0</sub>, EV<sub>DD1</sub>, V<sub>DD</sub> pins to an output pin.

- 2. However, do not exceed the total current value.
- **3.** Specification under conditions where the duty factor  $\leq$  70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

• Total output current of pins =  $(I_{OH} \times 0.7)/(n \times 0.01)$ 

<Example> Where n = 80% and IoH = -10.0 mA

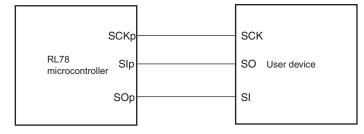
Total output current of pins =  $(-10.0 \times 0.7)/(80 \times 0.01) \approx -8.7$  mA

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

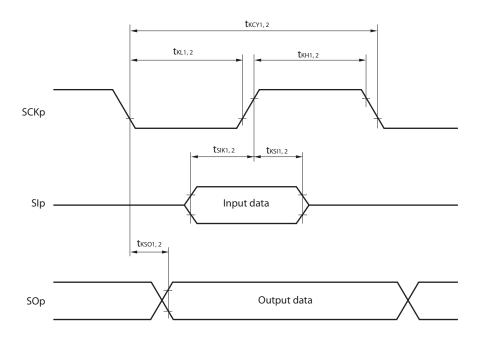
- **4.** The applied current for the products for industrial application (R5F100xxDxx, R5F101xxDxx, R5F100xxGxx) is -100 mA.
- Caution P00, P02 to P04, P10 to P15, P17, P43 to P45, P50, P52 to P55, P71, P74, P80 to P82, P96, and P142 to P144 do not output high level in N-ch open-drain mode.
- **Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.



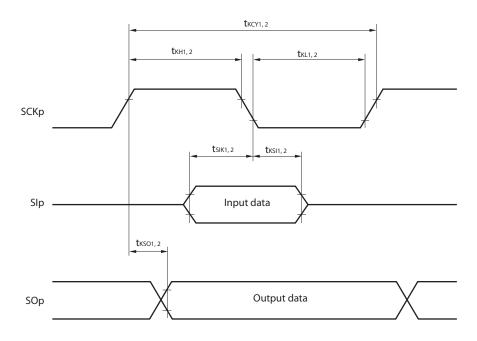
# CSI mode connection diagram (during communication at same potential)

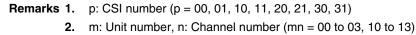


CSI mode serial transfer timing (during communication at same potential) (When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



CSI mode serial transfer timing (during communication at same potential) (When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)







Parameter	Symbol	nbol Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode	
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Data setup time (reception)	tsu:dat		1/fмск + 135 <sup>Note 3</sup>		1/fмск + 190 <sub>Note 3</sub>		1/fмск + 190 <sub>Note 3</sub>		kHz
		$\label{eq:loss} \begin{array}{l} 2.7 \ V \leq EV_{DD0} < 4.0 \ V, \\ 2.3 \ V \leq V_b \leq 2.7 \ V, \\ C_b = 50 \ pF, \ R_b = 2.7 \ k\Omega \end{array}$	1/fмск + 135 <sup>Note 3</sup>		1/fмск + 190 <sub>Note 3</sub>		1/fмск + 190 <sub>Note 3</sub>		kHz
			1/fмск + 190 <sup>Note 3</sup>		1/fмск + 190 <sub>Note 3</sub>		1/fмск + 190 <sub>Note 3</sub>		kHz
		$\label{eq:linear} \begin{array}{l} 2.7 \ V \leq EV_{DD0} < 4.0 \ V, \\ 2.3 \ V \leq V_b \leq 2.7 \ V, \\ C_b = 100 \ pF, \ R_b = 2.7 \ k\Omega \end{array}$	1/fмск + 190 <sup>Note 3</sup>		1/fмск + 190 <sub>Note 3</sub>		1/fмск + 190 <sub>Note 3</sub>		kHz
		$ \begin{split} & 1.8 \; V \leq EV_{DD0} < 3.3 \; V, \\ & 1.6 \; V \leq V_b \leq 2.0 \; V^{\text{Note 2}}, \\ & C_b = 100 \; pF, \; R_b = 5.5 \; k\Omega \end{split} $	1/f <sub>MCK</sub> + 190 <sup>Note 3</sup>		1/fмск + 190 <sub>Note 3</sub>		1/fмск + 190 <sub>Note 3</sub>		kHz
Data hold time (transmission)	thd:dat	$\begin{array}{l} 4.0 \; V \leq EV_{DD0} \leq 5.5 \; V, \\ 2.7 \; V \leq V_b \leq 4.0 \; V, \\ C_b = 50 \; pF, \; R_b = 2.7 \; k\Omega \end{array}$	0	305	0	305	0	305	ns
		$\label{eq:2.7} \begin{array}{l} 2.7 \ V \leq EV_{DD0} < 4.0 \ V, \\ 2.3 \ V \leq V_b \leq 2.7 \ V, \\ C_b = 50 \ pF, \ R_b = 2.7 \ k\Omega \end{array}$	0	305	0	305	0	305	ns
			0	355	0	355	0	355	ns
		$\label{eq:linear} \begin{array}{l} 2.7 \; V \leq EV_{DD0} < 4.0 \; V, \\ 2.3 \; V \leq V_b \leq 2.7 \; V, \\ C_b = 100 \; pF, \; R_b = 2.7 \; k\Omega \end{array}$	0	355	0	355	0	355	ns
		$\label{eq:VDD} \begin{split} & 1.8 \ V \leq EV_{\text{DD0}} < 3.3 \ V, \\ & 1.6 \ V \leq V_{\text{b}} \leq 2.0 \ V^{\text{Note 2}}, \\ & C_{\text{b}} = 100 \ \text{pF}, \ R_{\text{b}} = 5.5 \ \text{k}\Omega \end{split}$	0	405	0	405	0	405	ns

(10) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode) (2/2) (T<sub>A</sub> = -40 to +85°C. 1.8 V  $\leq$  EV<sub>DD0</sub> = EV<sub>DD1</sub>  $\leq$  V<sub>DD</sub>  $\leq$  5.5 V. Vss = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)

Notes 1. The value must also be equal to or less than f\_MCK/4.

- **2.** Use it with  $EV_{DD0} \ge V_b$ .
- 3. Set the fmck value to keep the hold time of SCLr = "L" and SCLr = "H".
- Caution Select the TTL input buffer and the N-ch open drain output (V<sub>DD</sub> tolerance (for the 20- to 52-pin products)/EV<sub>DD</sub> tolerance (for the 64- to 128-pin products)) mode for the SDAr pin and the N-ch open drain output (V<sub>DD</sub> tolerance (for the 20- to 52-pin products)/EV<sub>DD</sub> tolerance (for the 64- to 128-pin products)) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)



**Notes 1.** The first clock pulse is generated after this period when the start/restart condition is detected.

2. The maximum value (MAX.) of the is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.

- Caution The values in the above table are applied even when bit 2 (PIOR2) in the peripheral I/O redirection register (PIOR) is 1. At this time, the pin characteristics (IOH1, IOL1, VOH1, VOL1) must satisfy the values in the redirect destination.
- **Remark** The maximum value of Cb (communication line capacitance) and the value of Rb (communication line pull-up resistor) at that time in each mode are as follows.

Standard mode:  $C_b = 400 \text{ pF}, R_b = 2.7 \text{ k}\Omega$ 

<R>



# 2.6.2 Temperature sensor/internal reference voltage characteristics

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Temperature sensor output voltage	VTMPS25	Setting ADS register = 80H, $T_A = +25^{\circ}C$		1.05		V
Internal reference voltage	VBGR	Setting ADS register = 81H	1.38	1.45	1.5	V
Temperature coefficient	Fvtmps	Temperature sensor that depends on the temperature		-3.6		mV/°C
Operation stabilization wait time	tamp		5			μs

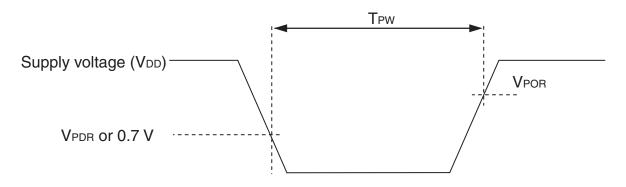
### (T<sub>A</sub> = -40 to +85°C, 2.4 V $\leq$ V<sub>DD</sub> $\leq$ 5.5 V, V<sub>SS</sub> = 0 V, HS (high-speed main) mode)

# 2.6.3 POR circuit characteristics

### $(T_A = -40 \text{ to } +85^{\circ}\text{C}, \text{ Vss} = 0 \text{ V})$

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Detection voltage	VPOR	Power supply rise time	1.47	1.51	1.55	V
	VPDR	Power supply fall time	1.46	1.50	1.54	V
Minimum pulse width <sup>Note</sup>	Tpw		300			μS

**Note** Minimum time required for a POR reset when V<sub>DD</sub> exceeds below V<sub>PDR</sub>. This is also the minimum time required for a POR reset from when V<sub>DD</sub> exceeds below 0.7 V to when V<sub>DD</sub> exceeds V<sub>POR</sub> while STOP mode is entered or the main system clock is stopped through setting bit 0 (HIOSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).





2.6.5 Power supply voltage rising slope characteristics

### $(T_A = -40 \text{ to } +85^{\circ}C, V_{SS} = 0 \text{ V})$

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	SVDD				54	V/ms

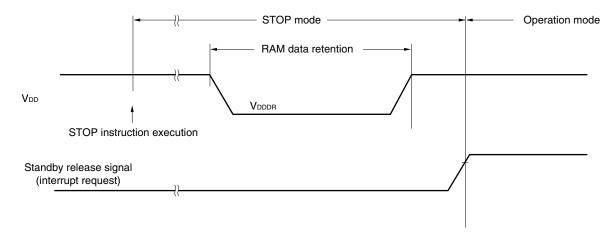
Caution Make sure to keep the internal reset state by the LVD circuit or an external reset until  $V_{DD}$  reaches the operating voltage range shown in 2.4 AC Characteristics.

### 2.7 RAM Data Retention Characteristics

### $(T_A = -40 \text{ to } +85^{\circ}\text{C}, \text{Vss} = 0 \text{ V})$

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention supply voltage	VDDDR		1.46 <sup>Note</sup>		5.5	V

**Note** This depends on the POR detection voltage. For a falling voltage, data in RAM are retained until the voltage reaches the level that triggers a POR reset but not once it reaches the level at which a POR reset is generated.





# 3. ELECTRICAL SPECIFICATIONS (G: INDUSTRIAL APPLICATIONS $T_A = -40$ to +105°C)

This chapter describes the following electrical specifications.

Target products G: Industrial applications  $T_A = -40$  to  $+105^{\circ}C$ R5F100xxGxx

- Cautions 1. The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.
  - 2. With products not provided with an EVDD0, EVDD1, EVSS0, or EVSS1 pin, replace EVDD0 and EVDD1 with VDD, or replace EVSS0 and EVSS1 with VSS.
  - 3. The pins mounted depend on the product. Refer to 2.1 Port Function to 2.2.1 Functions for each product.
  - 4. Please contact Renesas Electronics sales office for derating of operation under  $T_A = +85^{\circ}C$  to +105°C. Derating is the systematic reduction of load for the sake of improved reliability.

**Remark** When RL78/G13 is used in the range of  $T_A = -40$  to +85°C, see **CHAPTER 2 ELECTRICAL SPECIFICATIONS (T<sub>A</sub> = -40 to +85°C)**.

There are following differences between the products "G: Industrial applications ( $T_A = -40$  to  $+105^{\circ}C$ )" and the products "A: Consumer applications, and D: Industrial applications".

Parameter	Ap	pplication
	A: Consumer applications, D: Industrial applications	G: Industrial applications
Operating ambient temperature	T <sub>A</sub> = -40 to +85°C	T <sub>A</sub> = -40 to +105°C
Operating mode Operating voltage range	$\begin{array}{l} \text{HS (high-speed main) mode:} \\ \text{2.7 V} \leq V_{\text{DD}} \leq 5.5 \ \text{V@1 MHz to 32 MHz} \\ \text{2.4 V} \leq V_{\text{DD}} \leq 5.5 \ \text{V@1 MHz to 16 MHz} \\ \text{LS (low-speed main) mode:} \\ \text{1.8 V} \leq V_{\text{DD}} \leq 5.5 \ \text{V@1 MHz to 8 MHz} \\ \text{LV (low-voltage main) mode:} \\ \text{1.6 V} \leq V_{\text{DD}} \leq 5.5 \ \text{V@1 MHz to 4 MHz} \end{array}$	HS (high-speed main) mode only: 2.7 V $\leq$ V <sub>DD</sub> $\leq$ 5.5 V@1 MHz to 32 MHz 2.4 V $\leq$ V <sub>DD</sub> $\leq$ 5.5 V@1 MHz to 16 MHz
High-speed on-chip oscillator clock accuracy	$\begin{array}{l} 1.8 \ V \leq V_{DD} \leq 5.5 \ V \\ \pm 1.0\% @ \ T_{A} = -20 \ to \ +85^{\circ}C \\ \pm 1.5\% @ \ T_{A} = -40 \ to \ -20^{\circ}C \\ 1.6 \ V \leq V_{DD} < 1.8 \ V \\ \pm 5.0\% @ \ T_{A} = -20 \ to \ +85^{\circ}C \\ \pm 5.5\% @ \ T_{A} = -40 \ to \ -20^{\circ}C \end{array}$	$\begin{array}{l} 2.4 \ V \leq V_{DD} \leq 5.5 \ V \\ \pm 2.0\% @ \ T_{A} = +85 \ to \ +105^{\circ}C \\ \pm 1.0\% @ \ T_{A} = -20 \ to \ +85^{\circ}C \\ \pm 1.5\% @ \ T_{A} = -40 \ to \ -20^{\circ}C \end{array}$
Serial array unit	UART CSI: fcLk/2 (supporting 16 Mbps), fcLk/4 Simplified I <sup>2</sup> C communication	UART CSI: fcLK/4 Simplified I <sup>2</sup> C communication
IICA	Normal mode Fast mode Fast mode plus	Normal mode Fast mode
Voltage detector	Rise detection voltage: 1.67 V to 4.06 V (14 levels) Fall detection voltage: 1.63 V to 3.98 V (14 levels)	Rise detection voltage: 2.61 V to 4.06 V (8 levels) Fall detection voltage: 2.55 V to 3.98 V (8 levels)

(Remark is listed on the next page.)



Parameter	Symbols		Conditions	Ratings	Unit
Output current, high	Юн1	Per pin	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	-40	mA
		Total of all pins -170 mA	P00 to P04, P07, P32 to P37, P40 to P47, P102 to P106, P120, P125 to P127, P130, P140 to P145	-70	mA
			P05, P06, P10 to P17, P30, P31, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P90 to P97, P100, P101, P110 to P117, P146, P147	-100	mA
	Іон2	Per pin	P20 to P27, P150 to P156	-0.5	mA
		Total of all pins		-2	mA
Output current, low	Iol1	Per pin	P00 to P07, P10 to P17, P30 to P37, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100 to P106, P110 to P117, P120, P125 to P127, P130, P140 to P147	40	mA
		Total of all pins 170 mA	P00 to P04, P07, P32 to P37, P40 to P47, P102 to P106, P120, P125 to P127, P130, P140 to P145	70	mA
			P05, P06, P10 to P17, P30, P31, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P90 to P97, P100, P101, P110 to P117, P146, P147	100	mA
	IOL2	Per pin	P20 to P27, P150 to P156	1	mA
		Total of all pins		5	mA
Operating ambient	TA	In normal operati	on mode	-40 to +105	°C
temperature		In flash memory	programming mode		
Storage temperature	Tstg			-65 to +150	°C

# Absolute Maximum Ratings (TA = 25°C) (2/2)

- Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.
- **Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.



- **Notes 1.** Total current flowing into VDD, EVDDD, and EVDD1, including the input leakage current flowing when the level of the input pin is fixed to VDD, EVDDD, and EVDD1, or Vss, EVSSD, and EVSS1. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  - 2. During HALT instruction execution by flash memory.
  - 3. When high-speed on-chip oscillator and subsystem clock are stopped.
  - 4. When high-speed system clock and subsystem clock are stopped.
  - When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
  - 6. Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
  - 7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.

HS (high-speed main) mode: 2.7 V  $\leq$  V\_DD  $\leq$  5.5 V@1 MHz to 32 MHz 2.4 V  $\leq$  V\_DD  $\leq$  5.5 V@1 MHz to 16 MHz

- 8. Regarding the value for current operate the subsystem clock in STOP mode, refer to that in HALT mode.
- **Remarks 1.** fmx: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  - 2. file: High-speed on-chip oscillator clock frequency
  - 3. fsub: Subsystem clock frequency (XT1 clock oscillation frequency)
  - 4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is  $T_A = 25^{\circ}C$



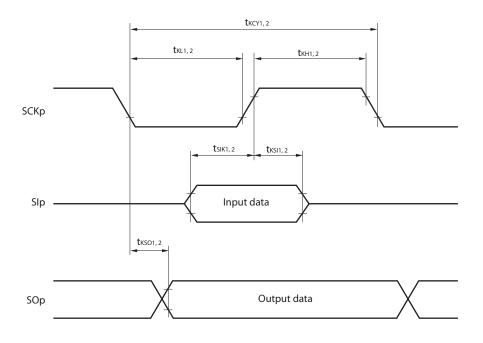
Parameter	Symbol		Conditions	MIN.	TYP.	MAX.	Unit
Low-speed on- chip oscillator operating current	FIL Note 1				0.20		μA
RTC operating current	IRTC Notes 1, 2, 3				0.02		μA
12-bit interval timer operating current	IT Notes 1, 2, 4				0.02		μA
Watchdog timer operating current	WDT Notes 1, 2, 5	fı∟ = 15 kHz			0.22		μA
A/D converter	ADC Notes 1, 6	When conversion	Normal mode, $AV_{REFP} = V_{DD} = 5.0 V$		1.3	1.7	mA
operating current	Notes 1, 6	at maximum speed	Low voltage mode, $AV_{REFP} = V_{DD} = 3.0 V$		0.5	0.7	mA
A/D converter reference voltage current	ADREF Note 1				75.0		μA
Temperature sensor operating current	ITMPS Note 1				75.0		μA
LVD operating current	LVD Notes 1, 7				0.08		μA
Self programming operating current	FSP Notes 1, 9				2.50	12.20	mA
BGO operating current	BGO Notes 1, 8				2.50	12.20	mA
SNOOZE	Isnoz	ADC operation	The mode is performed Note 10		0.50	1.10	mA
operating current	Note 1		The A/D conversion operations are performed, Loe voltage mode, $AV_{REFP} = V_{DD} = 3.0 V$		1.20	2.04	mA
		CSI/UART operatio	on		0.70	1.54	mA

## (3) Peripheral Functions (Common to all products) (TA = -40 to $+105^{\circ}$ C, 2.4 V $\leq$ EVDD0 = EVDD1 $\leq$ VDD $\leq$ 5.5 V, Vss = EVss0 = EVss1 = 0 V)

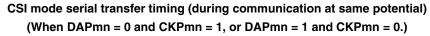
**Notes 1.** Current flowing to the VDD.

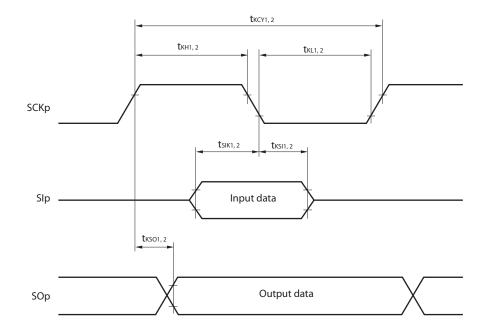
- 2. When high speed on-chip oscillator and high-speed system clock are stopped.
- 3. Current flowing only to the real-time clock (RTC) (excluding the operating current of the low-speed onchip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IRTC, when the real-time clock operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added. IDD2 subsystem clock operation includes the operational current of the real-time clock.
- 4. Current flowing only to the 12-bit interval timer (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IIT, when the 12-bit interval timer operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added.
- 5. Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The supply current of the RL78 is the sum of IDD1, IDD2 or IDD3 and IWDT when the watchdog timer operates.





# CSI mode serial transfer timing (during communication at same potential) (When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)





**Remarks 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31)

**2.** m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13)



# 3.8 Flash Memory Programming Characteristics

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
CPU/peripheral hardware clock frequency	fclĸ	$2.4~V \leq V_{DD} \leq 5.5~V$	1		32	MHz
Number of code flash rewrites Notes 1,2,3	Cerwr	Retained for 20 years TA = $85^{\circ}$ C <sup>Note 4</sup>	1,000			Times
Number of data flash rewrites Notes 1,2,3		Retained for 1 years TA = 25°C		1,000,000		
		Retained for 5 years TA = $85^{\circ}$ C <sup>Note 4</sup>	100,000			
		Retained for 20 years TA = 85°C <sup>Note 4</sup>	10,000			

 $(T_A = -40 \text{ to } +105^{\circ}\text{C}, 2.4 \text{ V} \le \text{V}_{DD} \le 5.5 \text{ V}, \text{V}_{SS} = 0 \text{ V})$ 

**Notes 1.** 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.

- 2. When using flash memory programmer and Renesas Electronics self programming library.
- **3.** These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.
- 4. This temperature is the average value at which data are retained.

## 3.9 Dedicated Flash Memory Programmer Communication (UART)

### $(T_{\text{A}} = -40 \text{ to } +105^{\circ}\text{C}, 2.4 \text{ V} \leq \text{EV}_{\text{DD0}} = \text{EV}_{\text{DD1}} \leq \text{V}_{\text{DD}} \leq 5.5 \text{ V}, \text{ V}_{\text{SS}} = \text{EV}_{\text{SS0}} = \text{EV}_{\text{SS1}} = 0 \text{ V})$

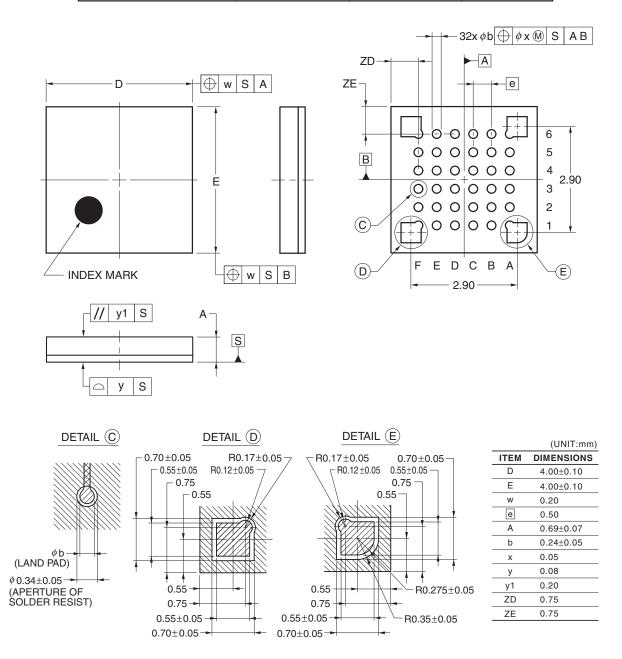
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		During serial programming	115,200		1,000,000	bps



# 4.6 36-pin Products

R5F100CAALA, R5F100CCALA, R5F100CDALA, R5F100CEALA, R5F100CFALA, R5F100CGALA R5F101CAALA, R5F101CCALA, R5F101CDALA, R5F101CEALA, R5F101CFALA, R5F101CGALA R5F100CAGLA, R5F100CCGLA, R5F100CDGLA, R5F100CEGLA, R5F100CFGLA, R5F100CGGLA

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-WFLGA36-4x4-0.50	PWLG0036KA-A	P36FC-50-AA4-2	0.023



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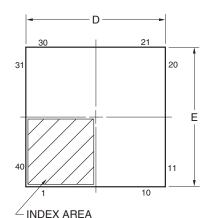
# 4.7 40-pin Products

R5F100EAANA, R5F100ECANA, R5F100EDANA, R5F100EEANA, R5F100EFANA, R5F100EGANA, R5F100EHANA R5F101EAANA, R5F101ECANA, R5F101EDANA, R5F101EEANA, R5F101EFANA, R5F101EGANA, R5F101EHANA R5F100EADNA, R5F100ECDNA, R5F100EDDNA, R5F100EEDNA, R5F100EFDNA, R5F100EGDNA, R5F100EHDNA

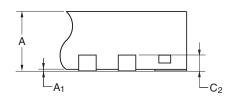
R5F101EADNA, R5F101ECDNA, R5F101EDDNA, R5F101EEDNA, R5F101EFDNA, R5F101EGDNA, R5F101EHDNA

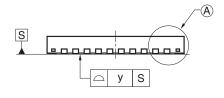
R5F100EAGNA, R5F100ECGNA, R5F100EDGNA, R5F100EEGNA, R5F100EFGNA, R5F100EGGNA, R5F100EHGNA

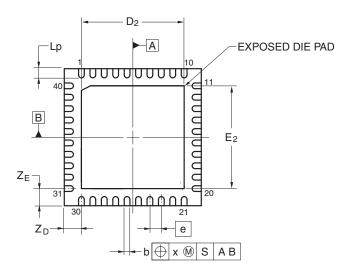
JEITA Package code	RENESAS code	Previous code	MASS (TYP.) [g]	
P-HWQFN40-6x6-0.50	PWQN0040KC-A	P40K8-50-4B4-5	0.09	



Detail of (A) Part







Referance	Dimens	sion in Mil	limeters
Symbol	Min	Nom	Max
D	5.95	6.00	6.05
E	5.95	6.00	6.05
A			0.80
A <sub>1</sub>	0.00		
b	0.18	0.25	0.30
е		0.50	
Lp	0.30	0.40	0.50
х			0.05
у			0.05
ZD		0.75	—
Z <sub>E</sub>		0.75	—
C <sub>2</sub>	0.15	0.20	0.25
D <sub>2</sub>		4.50	
E <sub>2</sub>		4.50	

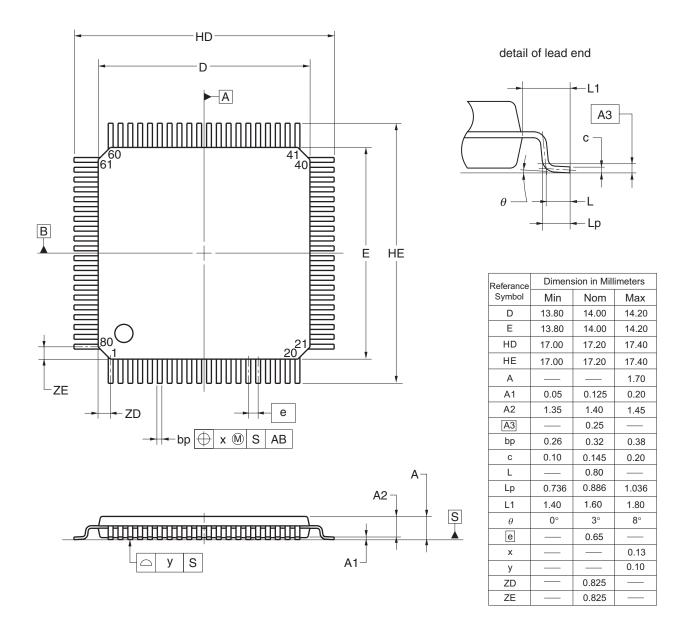
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# 4.12 80-pin Products

R5F100MFAFA, R5F100MGAFA, R5F100MHAFA, R5F100MJAFA, R5F100MKAFA, R5F100MLAFA R5F101MFAFA, R5F101MGAFA, R5F101MHAFA, R5F101MJAFA, R5F101MKAFA, R5F101MLAFA R5F100MFDFA, R5F100MGDFA, R5F100MHDFA, R5F100MJDFA, R5F100MKDFA, R5F100MLDFA R5F101MFDFA, R5F101MGDFA, R5F101MHDFA, R5F101MJDFA, R5F101MKDFA, R5F101MLDFA R5F100MFGFA, R5F100MGGFA, R5F100MHGFA, R5F100MJGFA

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LQFP80-14x14-0.65	PLQP0080JB-E	P80GC-65-UBT-2	0.69

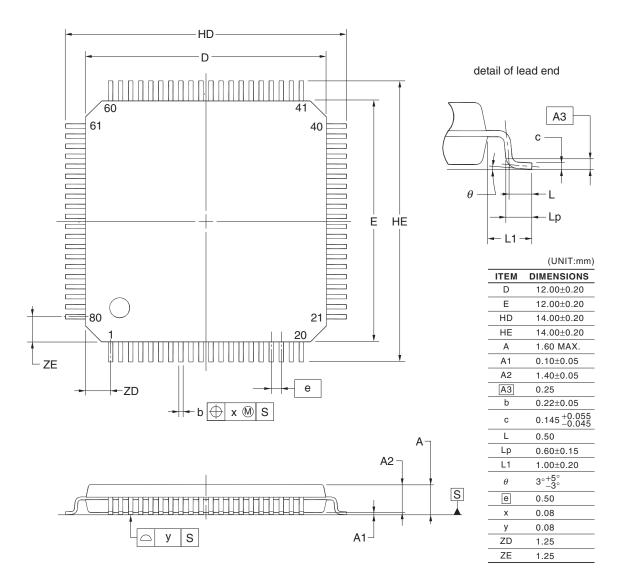


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R5F100MFAFB, R5F100MGAFB, R5F100MHAFB, R5F100MJAFB, R5F100MKAFB, R5F100MLAFB R5F101MFAFB, R5F101MGAFB, R5F101MHAFB, R5F101MJAFB, R5F101MKAFB, R5F101MLAFB R5F100MFDFB, R5F100MGDFB, R5F100MHDFB, R5F100MJDFB, R5F100MKDFB, R5F100MLDFB R5F101MFDFB, R5F101MGDFB, R5F101MHDFB, R5F101MJDFB, R5F101MKDFB, R5F101MLDFB R5F100MFGFB, R5F100MGGFB, R5F100MHGFB, R5F100MJGFB

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LFQFP80-12x12-0.50	PLQP0080KE-A	P80GK-50-8EU-2	0.53



### NOTE

Each lead centerline is located within 0.08 mm of its true position at maximum material condition.

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**Revision History** 

# RL78/G13 Data Sheet

		Description		
Rev.	Date	Page	Summary	
1.00	Feb 29, 2012	-	First Edition issued	
2.00	Oct 12, 2012	7	Figure 1-1. Part Number, Memory Size, and Package of RL78/G13: Pin count corrected.	
		25	1.4 Pin Identification: Description of pins INTP0 to INTP11 corrected.	
		40, 42, 44	1.6 Outline of Functions: Descriptions of Subsystem clock, Low-speed on-chip oscillator, and General-purpose register corrected.	
		41, 43, 45	1.6 Outline of Functions: Lists of Descriptions changed.	
		59, 63, 67	Descriptions of Note 8 in a table corrected.	
		68	(4) Common to RL78/G13 all products: Descriptions of Notes corrected.	
		69	2.4 AC Characteristics: Symbol of external system clock frequency corrected.	
		96 to 98	2.6.1 A/D converter characteristics: Notes of overall error corrected.	
		100	2.6.2 Temperature sensor characteristics: Parameter name corrected.	
		104	2.8 Flash Memory Programming Characteristics: Incorrect descriptions corrected.	
		116	3.10 52-pin products: Package drawings of 52-pin products corrected.	
		120	3.12 80-pin products: Package drawings of 80-pin products corrected.	
3.00	Aug 02, 2013	1	Modification of 1.1 Features	
		3	Modification of 1.2 List of Part Numbers	
		4 to 15	Modification of Table 1-1. List of Ordering Part Numbers, note, and caution	
		16 to 32	Modification of package type in 1.3.1 to 1.3.14	
		33	Modification of description in 1.4 Pin Identification	
		48, 50, 52	Modification of caution, table, and note in 1.6 Outline of Functions	
		55	Modification of description in table of Absolute Maximum Ratings ( $T_A = 25^{\circ}C$ )	
		57	Modification of table, note, caution, and remark in 2.2.1 X1, XT1 oscillator characteristics	
		57	Modification of table in 2.2.2 On-chip oscillator characteristics	
		58	Modification of note 3 of table (1/5) in 2.3.1 Pin characteristics	
		59	Modification of note 3 of table (2/5) in 2.3.1 Pin characteristics	
		63	Modification of table in (1) Flash ROM: 16 to 64 KB of 20- to 64-pin products	
		64	Modification of notes 1 and 4 in (1) Flash ROM: 16 to 64 KB of 20- to 64-pin products	
		65	Modification of table in (1) Flash ROM: 16 to 64 KB of 20- to 64-pin products	
		66	Modification of notes 1, 5, and 6 in (1) Flash ROM: 16 to 64 KB of 20- to 64- pin products	
		68	Modification of notes 1 and 4 in (2) Flash ROM: 96 to 256 KB of 30- to 100- pin products	
		70	Modification of notes 1, 5, and 6 in (2) Flash ROM: 96 to 256 KB of 30- to 100-pin products	
		72	Modification of notes 1 and 4 in (3) Flash ROM: 384 to 512 KB of 44- to 100- pin products	
		74	Modification of notes 1, 5, and 6 in (3) Flash ROM: 384 to 512 KB of 44- to 100-pin products	
		75	Modification of (4) Peripheral Functions (Common to all products)	
		77	Modification of table in 2.4 AC Characteristics	
		78, 79	Addition of Minimum Instruction Execution Time during Main System Clock Operation	
		80	Modification of figures of AC Timing Test Points and External System Clock Timing	